## NSN 5961-01-142-1110

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#### **Inclosure Material:**

Metal

**Overall Length:** 

0.328 inches

#### **Overall Diameter:**

0.875 inches

#### **Mounting Facility Quantity:**

2

#### **Internal Configuration:**

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

#### To-3

**Electrode Internally-electrically Connected To Case:** 

Collector

#### **Mounting Method:**

Unthreaded hole

### **Features Provided:**

Hermetically sealed case

#### **Semiconductor Material:**

Silicon

#### Voltage Rating In Volts Per Characteristic:

180.0 collector to base voltage/static/emitter open and 150.0 collector to emitter voltage/static/base open and 60.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

Between 20.00 amperes all primaries and 50.00 amperes all primaries

#### **Power Rating Per Characteristic:**

250.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### **Terminal Type And Quantity:**

1 case and 2 pin

#### **Specification Data:**

81349-mil-s-19500/514 government specification

#### Shelf Life:

N/a

#### Unit Of Measure:

- **Demilitarization:**

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